





## 0.2Amp Surface Mount Schottky Barrier Diode

### <u>0603</u>



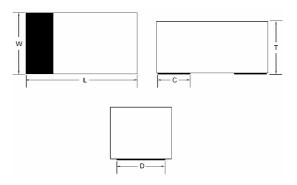


#### **Features**

- Designed for mounting on small surface
- Extremely thin/leadless package
- Low capacitance
- Low forward voltage drop
- High temperature soldering: 260°C/10 seconds at terminals
- Chip version in 0603

## **Mechanical Data**

- Case: 0603 Standard package, molded plastic
- Terminals: Gold plated, solderable per MIL-STD-750, method 2026.
- Polarity: Indicated by cathode band
- Mounting position: Any Package code: RZ
- Weight: 0.003 gram (approximately)



ITEM	0603		
L	0.071(1.80)		
	0.063(1.60)		
W	0.039(1.00)		
	0.031(0.80)		
Т	0.033(0.85)		
	0.027(0.70)		
С	0.018(0.45)		
	Typical		
D	0.028(0.70)		
	Typical		

**Dimensions in inches and (millimeters)** 

# **Maximum Ratings and Electrical characteristics**

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, denate current by 20%

Type Number	Symbol	0603	Units
Repetitive Peak Reverse Voltage	$V_{RRM}$	70	V
DC Reverse Voltage	V <sub>R</sub>	70	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	49	V
Average Forward Current	Io	70	mA
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I <sub>FSM</sub>	100	mA
Power Dissipation	Pd	150	mW
Forward Voltage IF=1mA IF=15mA	$V_{F}$	0.41 1.0	V
Reverse Leakage Current VR=25V	I <sub>R</sub>	0.1	uA
Typical capacitance between terminals VR=0V, f =1.0MHz reverse voltage	CJ	2	pF
Reverse Recovery Time (IF=IR=10mA, Irr=0.1 x IR, RL=100 $\Omega$ )	Trr	5	nS
Junction Temperature	TJ	-65 to + 125	°C
Storage Temperature	T <sub>STG</sub>	-65 to + 125	°C



#### RATINGS AND CHARACTERISTIC CURVES(TSS70U)

Fig. 1 - Forward characteristics

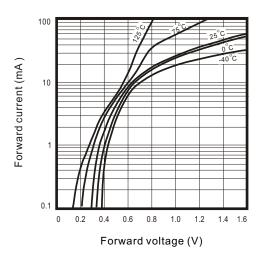


Fig.3 - Capacitance between terminals characteristics

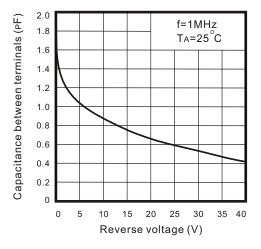


Fig. 2 - Reverse characteristics

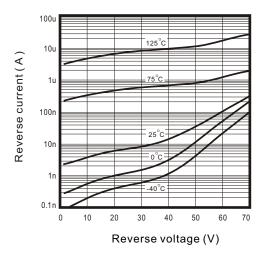
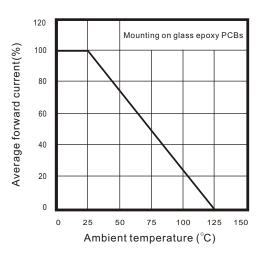


Fig.4 - Current derating curve



Version: A07